

	Type	Hits	Search Text
1	BRS	2	"6693935".pn.
2	BRS	2	"6495862".pn.
3	BRS	2	"5701321".pn.
4	BRS	2	"5862167".pn.
5	BRS	2	"11017223"
6	BRS	2	"11261109"
7	BRS	3	"11087850"
8	BRS	5	"10022565"
9	BRS	3	"06204609"
10	BRS	219	372/49.01.ccls.
11	BRS	2	"5862167".pn.
12	BRS	0	372/49.01.ccls. and (light near leak\$3 near prevent\$3)
13	BRS	114948	(semiconductor adj laser)(light near leak\$3 near prevent\$3)
14	BRS	31	(semiconductor adj laser) same (light near leak\$3 near prevent\$3)

	DBs	Time Stamp	Comments	Error Definition
1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 17:51		
2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 17:53		
3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 17:54		
4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 17:55		
5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 17:56		
6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 17:57		
7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 17:59		
8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 18:01		
9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 18:03		
10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 18:20		
11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 18:19		
12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 18:22		
13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/02 18:22		
14	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 12:26		

	Errors	Ref #
1		S1
2		S2
3		S3
4		S4
5		S5
6		S6
7		S7
8		S8
9		S9
10		S10
11		S11
12		S12
13		S13
14		S14

	Type	Hits	Search Text
15	BRS	9	(semiconductor adj laser) same (light near leak\$3 near prevent\$3) same (absor\$5 dielectric)
16	BRS	9	(semiconductor adj laser) same (light near prevent\$3) same dielectric
17	BRS	3907	(semiconductor adj laser) with led
18	BRS	138	(semiconductor adj laser) with led with gan
19	BRS	6	(semiconductor adj laser) same (leak\$3 near prevent\$3) same dielectric
20	BRS	21	(semiconductor adj laser) same (leak\$3 near light) same dielectric
21	BRS	2	"5862167".pn.
22	BRS	3101	(sapphire adj substrate) with gan
23	BRS	1415	((sapphire adj substrate) with gan) with (semiconductor adl laser)

	DBs	Time Stamp	Comments	Error Definition
15	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 12:41		
16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:30		
17	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:07		
18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:07		
19	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:41		
20	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:47		
21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:50		
22	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:51		
23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/11/03 13:52		

	Errors	Ref #
15		S15
16		S16
17		S17
18		S18
19		S19
20		S20
21		S21
22		S22
23		S23